# NSN 5961-01-206-4137

Semiconductor Device Set - Page 1 of 1



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#### **Inclosure Material:**

Ceramic all semiconductor device diode and metal all semiconductor device diode

### **Overall Length:**

1.000 inches all semiconductor device diode

#### Overall Diameter:

0.620 inches all semiconductor device diode

### **Mounting Facility Quantity:**

1 all semiconductor device diode

#### **Component Function Relationship:**

Matched

### **Component Name And Quantity:**

2 semiconductor device diode

#### **Mounting Method:**

Threaded stud all semiconductor device diode

#### **Semiconductor Material:**

Silicon all semiconductor device diode

### Voltage Rating In Volts Per Characteristic:

1.0 forward voltage, dc all semiconductor device diode

### **Capacitance Rating In Picofarads:**

0.23 all semiconductor device diode and 0.27 all semiconductor device diode

### **Maximum Operating Tempurature Per Measurement Point:**

150.0 degrees celsius ambient air all semiconductor device diode

### **Test Data Document:**

53711-6116243 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Terminal Type And Quantity:**

1 case all semiconductor device diode and 1 threaded stud all semiconductor device diode

### Shelf Life:

N/a

### **Unit Of Measure:**

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### Demilitarization:

Yes - demil/mli

### Fiig:

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